



T0610H/T0620H/T0635H/T0650H Series 6A TRIACs

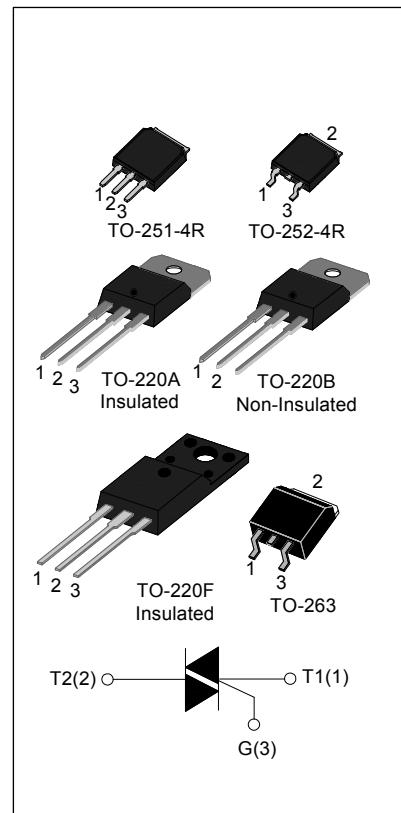
Rev.8.0

DESCRIPTION:

T06xxH series triacs of high junction temperature with high dv/dt rate with strong resistance to electromagnetic interference provide high ability to withstand the shock loading of large current. They are especially recommended for use on inductive load and high environment temperature condition.

From all three terminals to external heatsink, T06xxH-xxA provides a rated insulation voltage of 2500 V_{RMS}, and

T06xxH-xxF provides a rated insulation voltage of 2000 V_{RMS}, complying with UL standards (File ref: E252906).



MAIN FEATURES

Symbol	Value	Unit
I _{T(RMS)}	6	A
V _{DRM} /V _{RRM}	600 and 800	V
T _{jmax}	150	°C

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	T _{stg}	-40-150	°C
Operating junction temperature range	T _j	-40-150	°C
Repetitive peak off-state voltage(T _j =25°C)	V _{DRM}	600/800	V
Repetitive peak reverse voltage(T _j =25°C)	V _{RRM}	600/800	V
Non repetitive surge peak Off-state voltage	V _{DSM}	V _{DRM} + 100	V
Non repetitive peak reverse voltage	V _{RSM}	V _{RRM} + 100	V
RMS on-state current	I _{T(RMS)}	6	A

RMS on-state current	TO-263 ($T_C=113^\circ\text{C}$)	$I_{T(\text{RMS})}$	6	A
Non repetitive surge peak on-state current (full cycle, $F=50\text{Hz}$)		I_{TSM}	60	A
I^2t value for fusing ($tp=10\text{ms}$)		I^2t	21	A^2s
Critical rate of rise of on-state current ($I_G=2 \times I_{GT}$)		dI/dt	50	$\text{A}/\mu\text{s}$
Peak gate current		I_{GM}	4	A
Average gate power dissipation		$P_{G(AV)}$	1	W
Peak gate power		P_{GM}	5	W

ELECTRICAL CHARACTERISTICS ($T_j=25^\circ\text{C}$ unless otherwise specified)

Symbol	Test Condition	Quadrant	Value				Unit	
			T0610H	T0620H	T0635H	T0650H		
I_{GT}	$V_D=12\text{V}$ $R_L=33\Omega$	I - II -III	MAX	10	20	35	50	mA
V_{GT}		I - II -III	MAX	1.3				V
V_{GD}	$V_D=V_{DRM}$ $T_j=150^\circ\text{C}$ $R_L=3.3\text{K}\Omega$	I - II -III	MIN	0.2				V
I_L	$I_G=1.2I_{GT}$	I -III	MAX	20	40	50	70	mA
		II		35	55	70	100	
I_H	$I_T=100\text{mA}$	MAX	20	30	45	60		mA
dV/dt	$V_D=2/3V_{DRM}$ $R_{GK}=1\text{K}\Omega$ $T_j=150^\circ\text{C}$	MIN	200	500	1000	1500		$\text{V}/\mu\text{s}$

STATIC CHARACTERISTICS

Symbol	Parameter		Value(MAX)		Unit	
V_{TM}	$I_{TM}=8.5\text{A}$ $tp=380\mu\text{s}$		$T_j=25^\circ\text{C}$		1.4	V
I_{DRM}	$V_D=V_{DRM}$ $V_R=V_{RRM}$		$T_j=25^\circ\text{C}$		5	μA
I_{RRM}			$T_j=150^\circ\text{C}$		1	mA

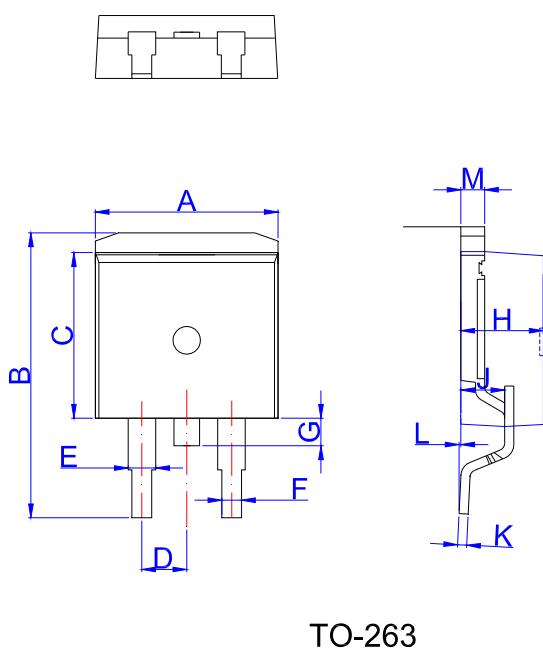
THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	junction to case(AC)	TO-251-4R/ TO-252-4R	°C/W
		TO-220A(Ins)	
		TO-220B(Non-Ins)	
		TO-220F(Ins)	
		TO-263	

ORDERING INFORMATION

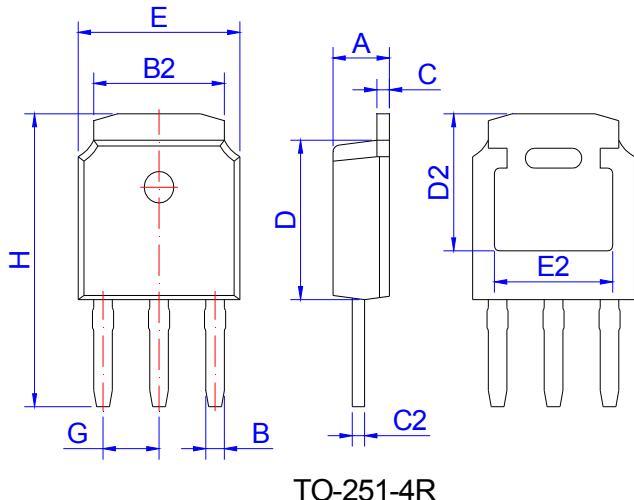
T	06	20	H	-6	F	E:TO-263 A:TO-220A(Ins) F:TO-220F(Ins) B:TO-220B(Non-Ins) H:TO-251-4R K:TO-252-4R
Triacs		$I_{T(RMS)}:6A$				6: $V_{DRM} / V_{RRM} \geq 600V$ 8: $V_{DRM} / V_{RRM} \geq 800V$ High junction temperature

PACKAGE MECHANICAL DATA

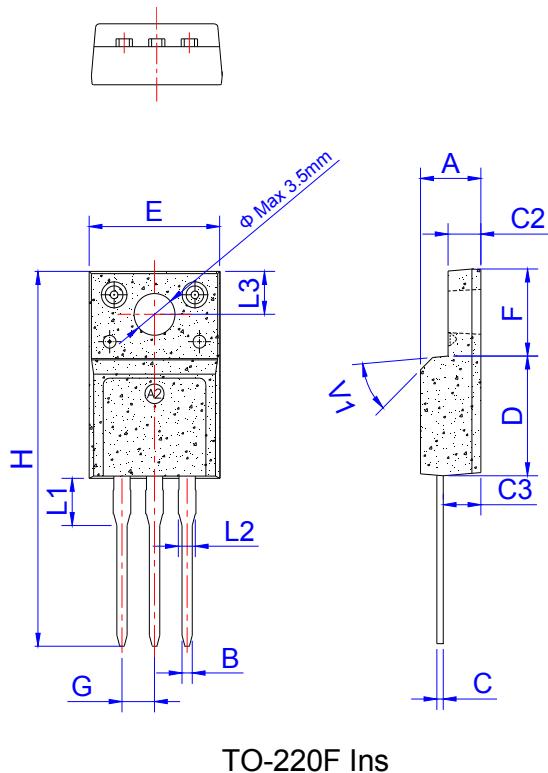


Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	9.90		10.20	0.390		0.402
B	14.70		15.80	0.579		0.622
C	9.4		9.6	0.37		0.378
D		2.54			0.100	
E	1.20		1.40	0.047		0.055
F	0.75		0.85	0.029		0.033
G			1.75			0.069
H	4.40		4.70	0.173		0.185
J	2.30		2.70	0.091		0.106
K	0.38		0.55	0.015		0.022
L	0	0.10	0.25	0	0.004	0.010
M	1.25		1.35	0.049		0.053

PACKAGE MECHANICAL DATA

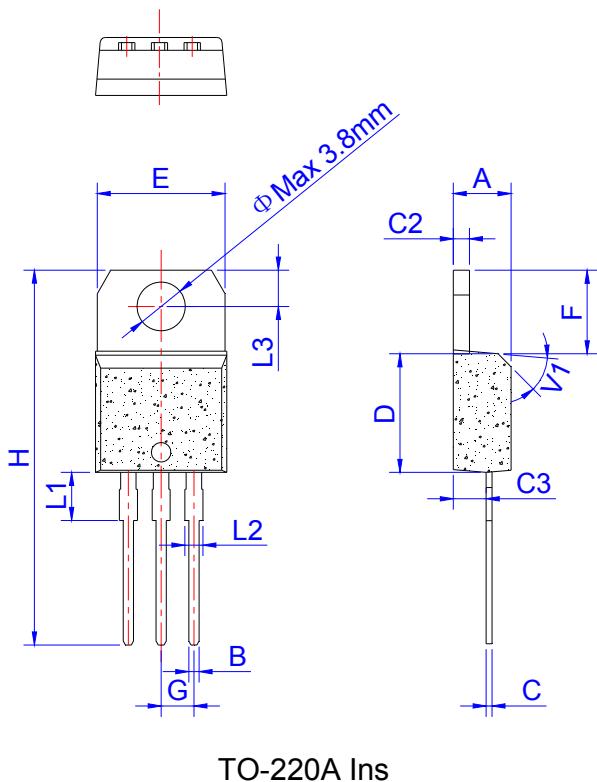


Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.10	2.30	2.50	0.083	0.091	0.098
B	0.66	0.76	0.86	0.026	0.030	0.034
B2	5.15	5.33	5.48	0.203	0.210	0.216
C	0.44	0.51	0.58	0.017	0.020	0.023
C2	0.44	0.51	0.58	0.017	0.020	0.023
D	5.90	6.10	6.30	0.232	0.240	0.248
D2	5.30 REF			0.209 REF		
E	6.40	6.60	6.80	0.252	0.260	0.268
E2	4.83 REF			0.190 REF		
G	2.19	2.29	2.39	0.086	0.090	0.094
H	10.60	11.20	11.80	0.417	0.441	0.465

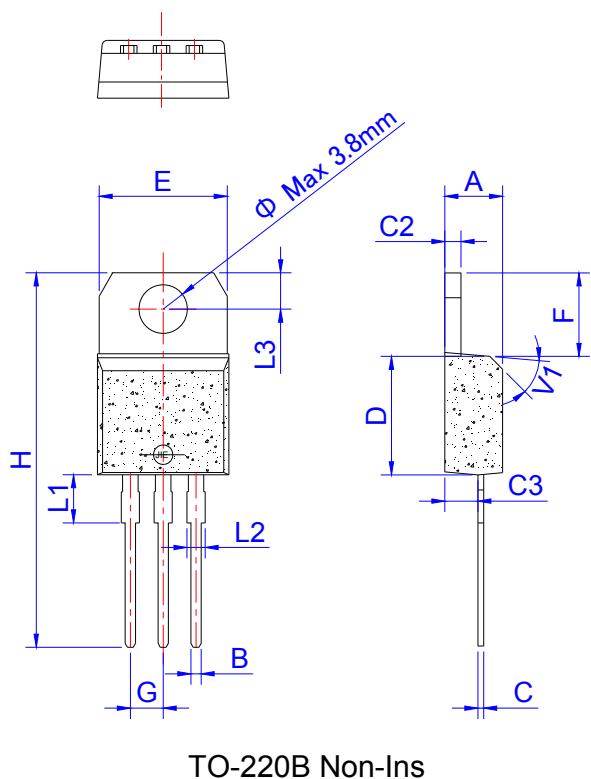


Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.50		4.90	0.177		0.193
B	0.74	0.80	0.83	0.029	0.031	0.033
C	0.47		0.65	0.019		0.026
C2	2.45		2.75	0.096		0.108
C3	2.60		3.00	0.102		0.118
D	8.80		9.30	0.346		0.366
E	9.80		10.4	0.386		0.410
F	6.40		6.80	0.252		0.268
G		2.54			0.1	
H	28.0		29.8	1.102		1.173
L1		3.63			0.143	
L2	1.14		1.70	0.045		0.067
L3		3.30			0.130	
V1		45°			45°	

PACKAGE MECHANICAL DATA

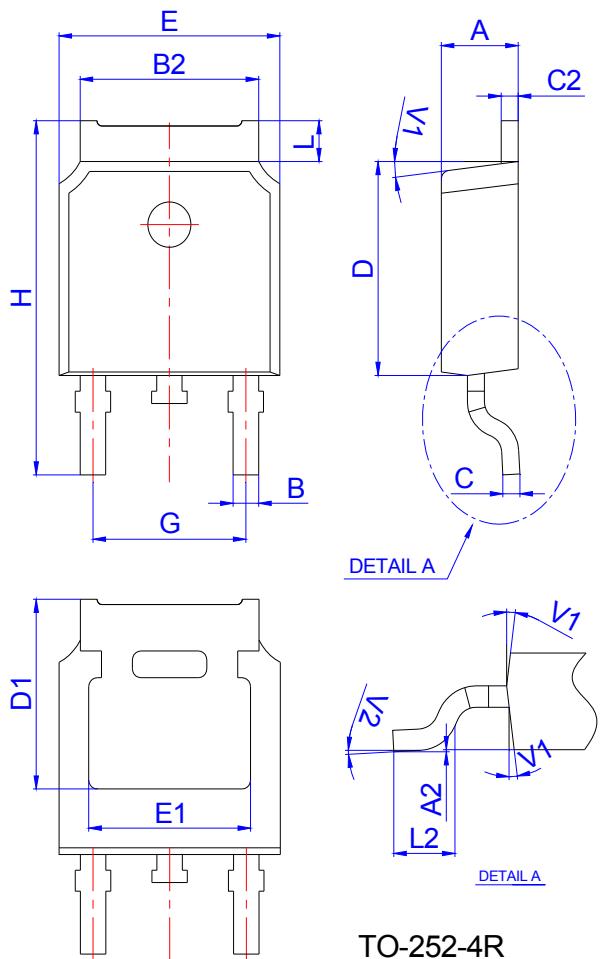


Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	0.61		0.88	0.024		0.035
C	0.46		0.70	0.018		0.028
C2	1.21		1.32	0.048		0.052
C3	2.40		2.72	0.094		0.107
D	8.60		9.70	0.339		0.382
E	9.80		10.4	0.386		0.409
F	6.55		6.95	0.258		0.274
G		2.54			0.1	
H	28.0		29.8	1.102		1.173
L1		3.75			0.148	
L2	1.14		1.70	0.045		0.067
L3	2.65		2.95	0.104		0.116
V1		45°			45°	



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	0.61		0.88	0.024		0.035
C	0.46		0.70	0.018		0.028
C2	1.21		1.32	0.048		0.052
C3	2.40		2.72	0.094		0.107
D	8.60		9.70	0.339		0.382
E	9.60		10.4	0.378		0.409
F	6.20		6.60	0.244		0.260
G		2.54			0.1	
H	28.0		29.8	1.102		1.173
L1		3.75			0.148	
L2	1.14		1.70	0.045		0.067
L3	2.65		2.95	0.104		0.116
V1		45°			45°	

PACKAGE MECHANICAL DATA



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.10		2.50	0.083		0.098
A2	0		0.10	0		0.004
B	0.66		0.86	0.026		0.034
B2	5.18		5.48	0.202		0.216
C	0.40		0.60	0.016		0.024
C2	0.44		0.58	0.017		0.023
D	5.90		6.30	0.232		0.248
D1	5.30REF			0.209REF		
E	6.40		6.80	0.252		0.268
E1	4.63			0.182		
G	4.47		4.67	0.176		0.184
H	9.50		10.70	0.374		0.421
L	1.09		1.21	0.043		0.048
L2	1.35		1.65	0.053		0.065
V1		7°			7°	
V2	0°		6°	0°		6°

FIG.1: Maximum power dissipation versus RMS on-state current

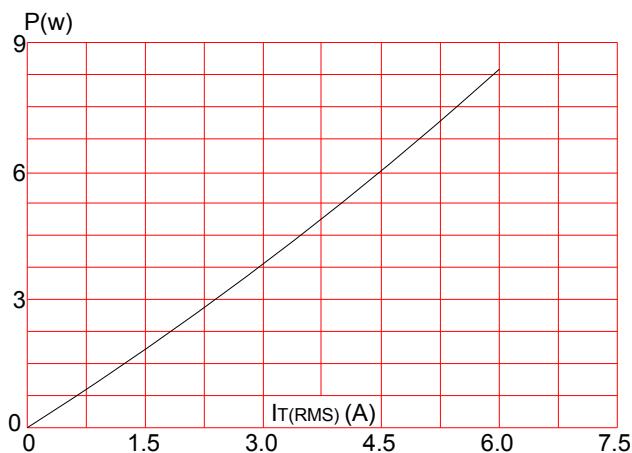


FIG.2: RMS on-state current versus case temperature

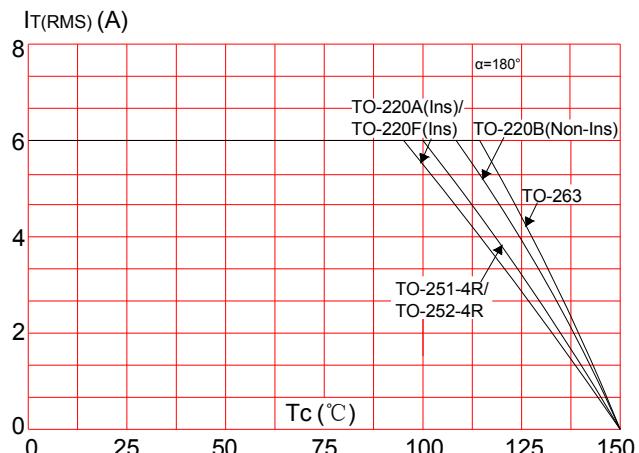


FIG.3: Surge peak on-state current versus number of cycles

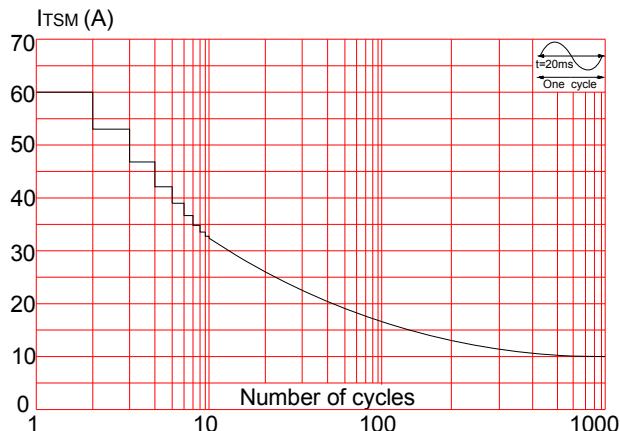


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 20\text{ms}$, and corresponding value of I^2t ($\text{d}I/\text{dt} < 50\text{A}/\mu\text{s}$)

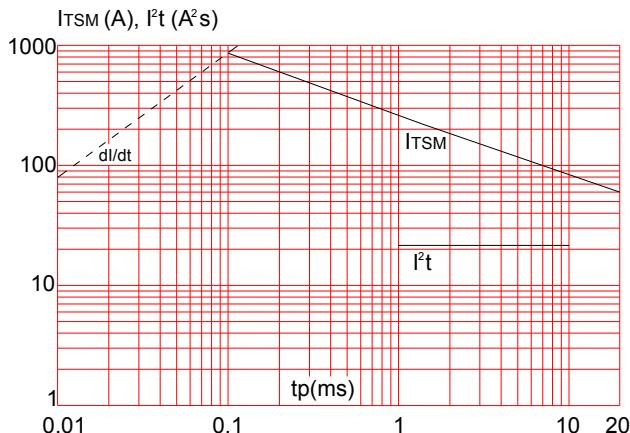


FIG.4: On-state characteristics (maximum values)

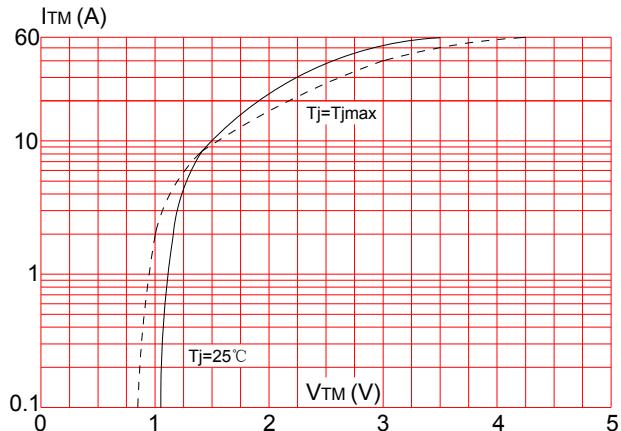
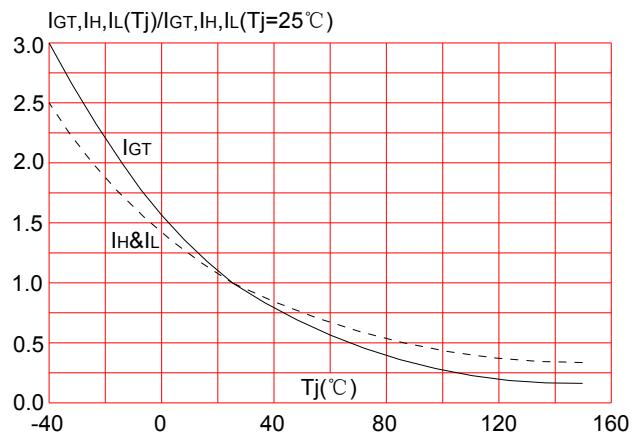


FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature



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